

AR0135CS

CMOS Image Sensor, Digital, Global Shutter, 1.2 MP, 1/3"

Product Overview

For complete documentation, see the data sheet.

This 1/3-inch format, 1.2 MP imaging device has been designed to address the challenging requirements of Industrial, consumer and IoT applications. The new global shutter sensor allows the camera to “freeze” fast moving scene data, and ensures effective synchronization with pulsed light sources. The AR0135 sensor incorporates a new innovative global shutter pixel design, with 10X lower dark current and 4X higher shutter efficiency vs. previous generation products. These improvements allow the sensor to produce clear, low-noise images, in both low-light and bright scenes, and in high temperature environments. This performance enables the required eye tracking and gesture detection functionality in 3D scanner, gesture recognition devices.

Features

- ON Semiconductor's Next Generation Global Shutter Technology
- Superior Low-light Performance
- HD Video (720p60)
- Video/Single Frame Mode
- Flexible Row-skip Modes
- On-chip AE and Statistics Engine
- Parallel and Serial Output
- Support for External LED or Flash
- Auto Black Level Calibration
- Context Switching

For more features, see the data sheet

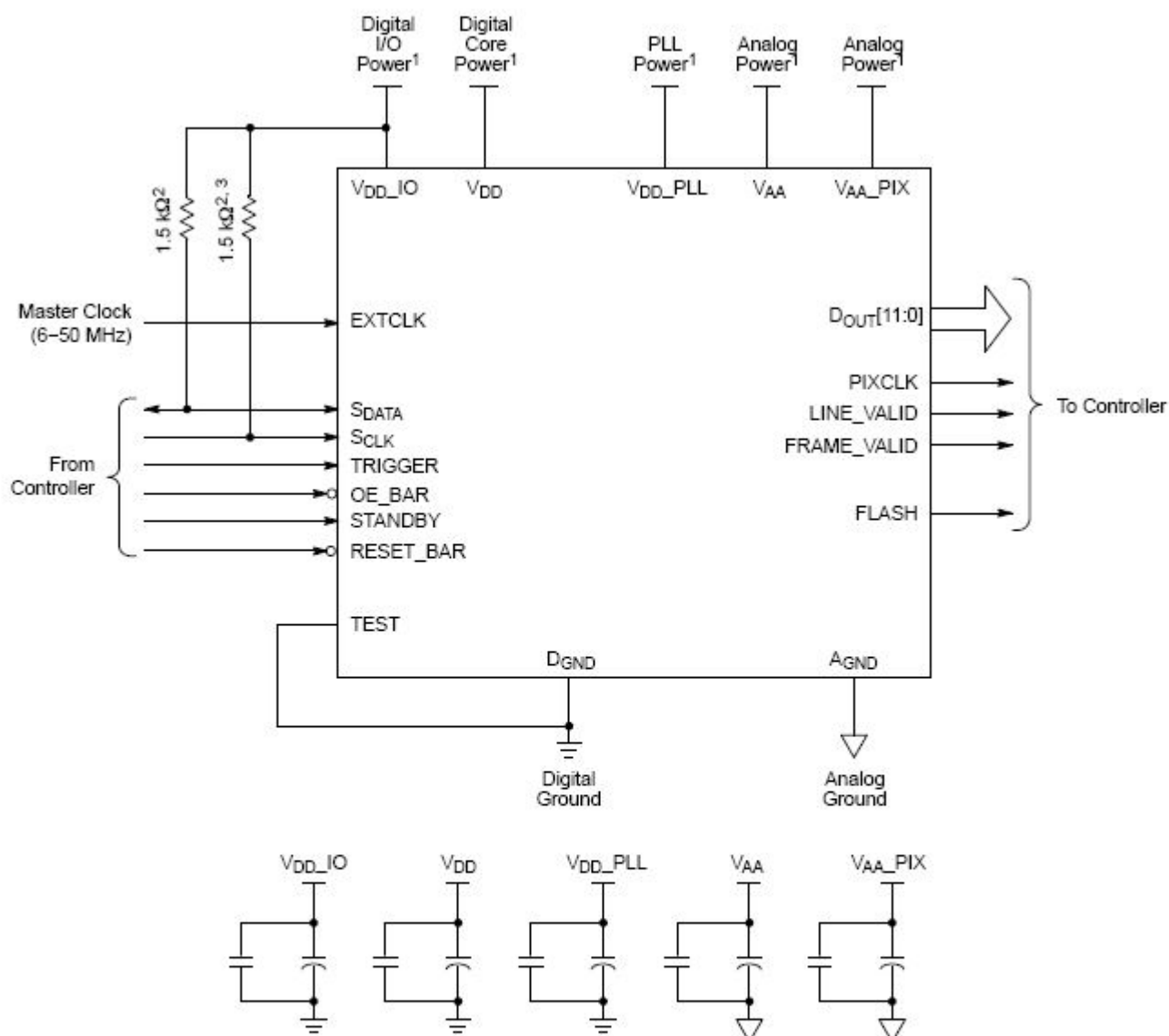
Applications

- Barcode scanner
- 3D scanning
- Positional tracking
- Iris Scanning
- Augmented Reality

Part Electrical Specifications

Product	Pricing (\$/Unit)	Compliance	Status	Type	Megapixels	Frame Rate (fps)	Optical Format	Shutter Type	Pixel Size (µm)	Output Interface	Color	Package Type
AR0135CS2C00 SUEA0-DPBR		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		RGB	IBGA-63
AR0135CS2C00 SUEA0-DPBR1		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		RGB	IBGA-63
AR0135CS2C00 SUEA0-DRBR		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		RGB	IBGA-63
AR0135CS2C19 SUEA0-DRBR		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		RGB	IBGA-63
AR0135CS2M00 SUEA0-DPBR		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		Mono	IBGA-63
AR0135CS2M00 SUEA0-DPBR1		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		Mono	IBGA-63
AR0135CS2M00 SUEA0-DRBR		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		Mono	IBGA-63
AR0135CS2M25 SUD20		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		Mono	
AR0135CS2M25 SUEA0-DPBR		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		Mono	IBGA-63
AR0135CS2M25 SUEA0-DPBR1		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		Mono	IBGA-63
AR0135CS2M25 SUEA0-DRBR		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		Mono	IBGA-63
AR0135CS2M25 SUEA0-DRBR1		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		Mono	IBGA-63
AR0135CS2M25 SUEA0-TPBR		Pb H	Active	CMOS	1.2		1/3 inch	Global Shutter	3.75 x 3.75		Mono	IBGA-63

Application Diagram



Notes:

1. All power supplies must be adequately decoupled.
2. ON Semiconductor recommends a resistor value of 1.5 k Ω , but a greater value may be used for slower two-wire speed.
3. This pull-up resistor is not required if the controller drives a valid logic level on SCLK at all times.
4. The serial interface output pads can be left unconnected if the parallel output interface is used.
5. ON Semiconductor recommends that 0.1 μ F and 10 μ F decoupling capacitors for each power supply are mounted as close as possible to the pad. Actual values and results may vary depending on the layout and design considerations. Refer to the AR0135CS demo headboard schematics for circuit recommendations.
6. ON Semiconductor recommends that analog power planes be placed in a manner such that coupling with the digital power planes is minimized.